

www.vishay.com

**Vishay Semiconductors** 

## ADD-A-PAK Generation VII Power Modules Standard Diodes, 100 A



ADD-A-PAK

PRODUCT SUMMARY				
I <sub>F(AV)</sub>	100 A			
Туре	Modules - Diode, High Voltage			

### **MECHANICAL DESCRIPTION**

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- High voltage
- Industrial standard package
- UL approved file E78996
- Low thermal resistance
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	112 °C	100					
I <sub>F(RMS)</sub>		157	А				
I <sub>FSM</sub>	50 Hz	2020	A				
	60 Hz	2115					
l <sup>2</sup> t	50 Hz	20.41	kA <sup>2</sup> s				
	60 Hz	18.63	KA-S				
l²√t		204.1	kA²√s				
V <sub>RRM</sub>	Range	400 to 1600	V				
TJ		- 40 to 150	°C				
T <sub>Stg</sub>		- 40 10 150	U				

(Pb) RoHS



www.vishay.com

## **Vishay Semiconductors**

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA			
	04	400	500				
06		600	700				
	08	800	900				
VSK.91	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CON	DITIONS	VALUES	UNITS
Maximum average forward current at case temperature	I <sub>F(AV)</sub>	180° condu	ction, half sine	100 112	A °C	
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 90 °C	case temperat	ure	157	0
		t = 10 ms	No voltage		2020	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		2115	А
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave,	1700	
		t = 8.3 ms	reapplied		1780	
	l <sup>2</sup> t	t = 10 ms	No voltage	intitial $T_J = T_J$ maximum	20.41	kA <sup>2</sup> s
		t = 8.3 ms	reapplied		18.63	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		14.44	
		t = 8.3 ms	reapplied		13.18	
Maximum I²√t for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	204.1	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	(I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum	0.76	V
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)})$	), T <sub>J</sub> = T <sub>J</sub> maxir	0.89	V	
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi$	2.4	mΩ	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)})$	), T <sub>J</sub> = T <sub>J</sub> maxir	num	2.05	11152
Maximum forward voltage drop	V <sub>FM</sub>	$I_{FM} = \pi \times I_{F(x)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C,	t <sub>p</sub> = 400 μs square wave	1.55	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA			
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V			

Revision: 06-Jun-12 2 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



www.vishay.com

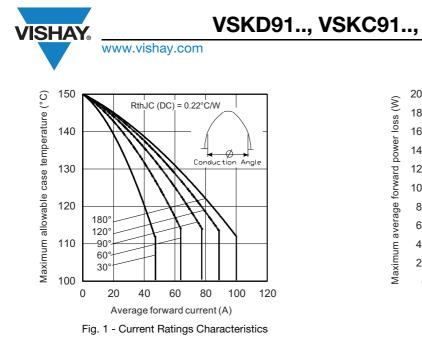
## Vishay Semiconductors

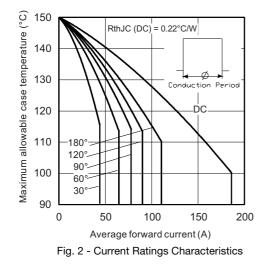
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Junction and storage tempe	erature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C	
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.22	°C/W	
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	0/10	
Mounting torque + 10.0/	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm	
Mounting torque ± 10 % –	busbar		3 hours to allow for the spread of the compound.	3	INITI	
Approximate weight				75	g	
				2.7	oz.	
Case style			JEDEC	ADD-A-PAK Gen. VII (TO-2		

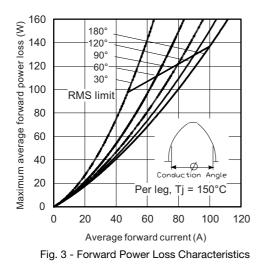
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	<b>30</b> °	
VSK.91	0.057	0.068	0.087	0.12	0.177	0.045	0.073	0.093	0.123	0.178	°C/W

Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

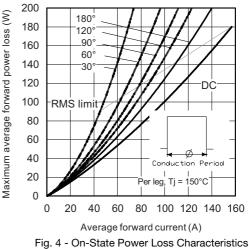


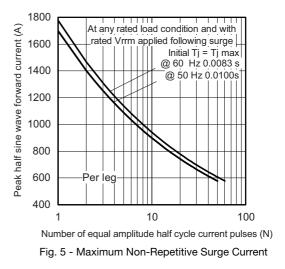






**Vishay Semiconductors** 





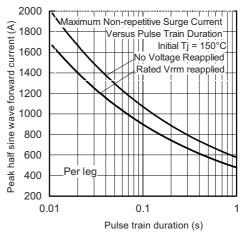


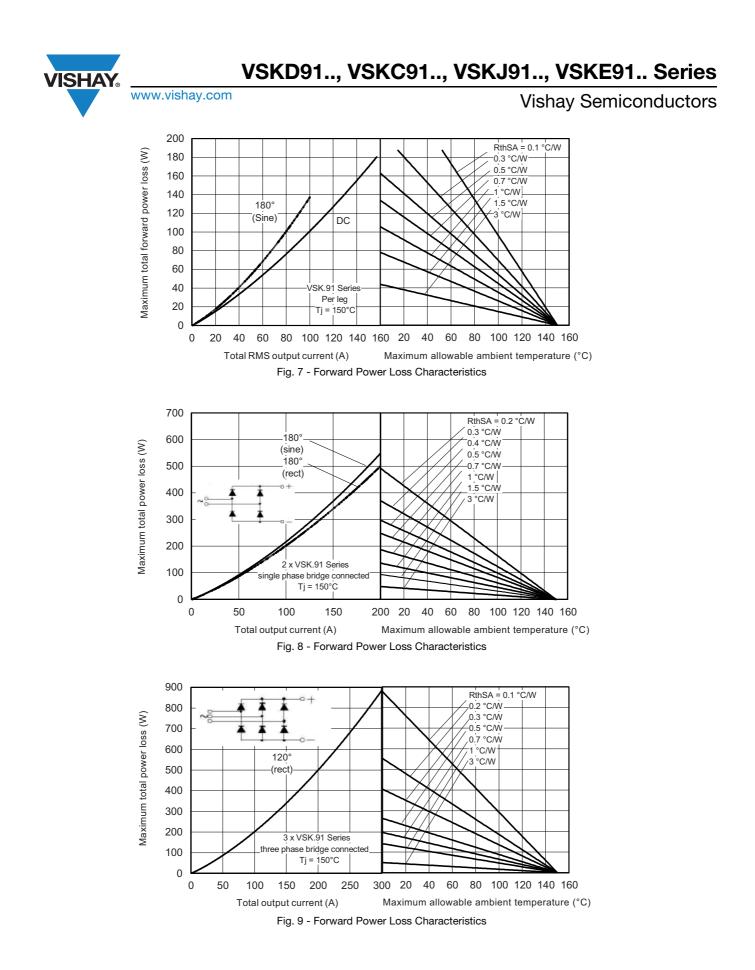
Fig. 6 - Maximum Non-Repetitive Surge Current

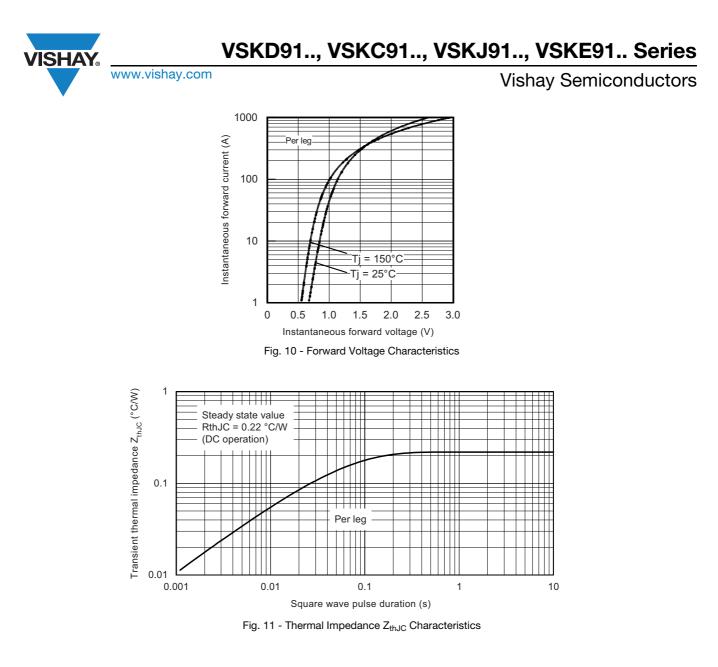
Revision: 06-Jun-12

4

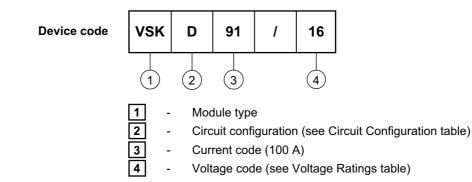
Document Number: 94627

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





### **ORDERING INFORMATION TABLE**



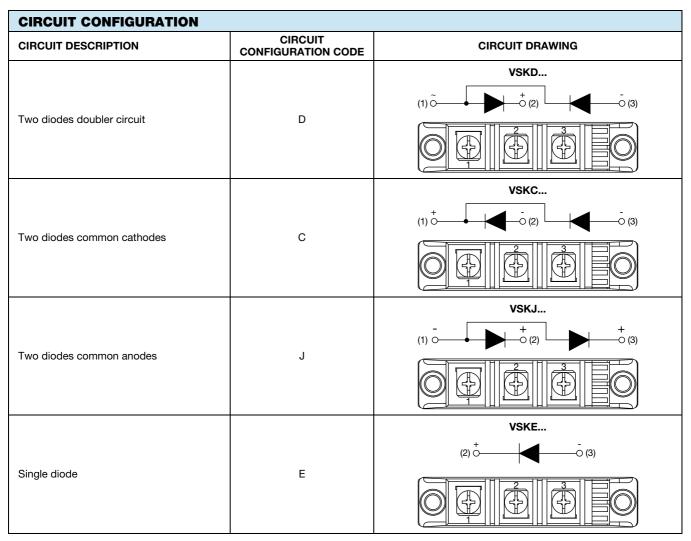
#### Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>



www.vishay.com

**Vishay Semiconductors** 



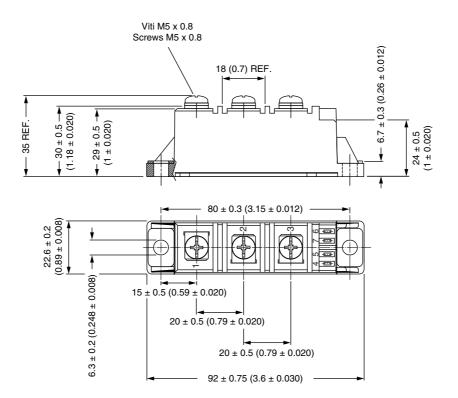
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



**Vishay Semiconductors** 



**DIMENSIONS** in millimeters (inches)







www.vishay.com

Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.